
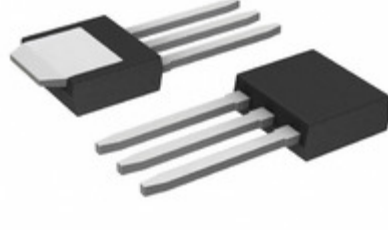


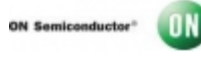
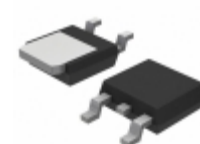
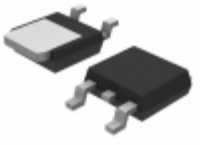
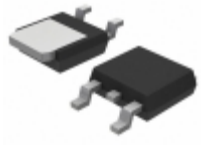
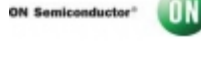

	<h2 style="color: red;">NTD3055L104-1G</h2>
	<p><b>Hersteller-Teilenummer:</b> NTD3055L104-1G</p> <p><b>Hersteller / Marke:</b> AMI Semiconductor / ON Semiconductor</p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 60V 12A IPAK</p> <p><b>Datenblätter:</b>  <a href="#">NTD3055L104-1G.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 28510 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	NTD3055L104-1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 60V 12A IPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	28510 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (Tj)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-251-3 Short Leads, IPak, TO-251AA
Supplier Device-Gehäuse	I-Pak
Verlustleistung (max)	1.5W (Ta), 48W (Tj)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	12A (Ta)
Rds On (Max) @ Id, Vgs	104 mOhm @ 6A, 5V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	20nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	440pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	5V
Vgs (Max)	±15V
Verpackung	Tube

NTD3055L104-1G ist neu im Original, Suche NTD3055L104-1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTD3055L104-1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTD3055L104-1G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p><b>NTD3055L04T4G</b> ON NTD3055L04T4G ON</p>	 <p><b>NTD3055L</b> FAI NTD3055L FAI</p>	 <p><b>NTD3055L104T4G</b> AMI Semiconductor / ON Semiconductor NTD3055L104T4G ON</p>	 <p><b>NTD3055L170</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 9A DPAK</p>
 <p><b>NTD3055L104</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 12A DPAK</p>	 <p><b>NTD3055L104G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 12A DPAK</p>	 <p><b>NTD3055L104T4</b> AMI Semiconductor / ON Semiconductor NTD3055L104T4 ON</p>	 <p><b>NTD3055L-170T4G</b> ON NTD3055L-170T4G ON</p>

### heiße Teile

Mehr

NTD2955-1	NTD2955-1G	NTD2955D	NTD2955E	NTD2955G
NTD2955PT4G	NTD2955T4	NTD2955T4G	NTD2955V	NTD2955VT4G
NTD3055-094	NTD3055-094-1G	NTD3055-094G	NTD3055-094T4	NTD3055-094T4G
NTD3055-150	NTD3055-150-1G	NTD3055-150G	NTD3055-150T4	NTD3055-150T4G
NTD3055-170T4G	NTD3055L104T4G	NTD3055L	NTD3055L04T4G	NTD3055L104
NTD3055L104G	NTD3055L104T4G	NTD3055L170	NTD3055L170-001	NTD3055L170-1G
NTD3055L170G	NTD3055L170T4	NTD3055L170T4G	NTD3055LT4G	NTD3055VLT4G
NTD30N02G	NTD30N02T4	NTD30N02T4G	NTD30N06RT4	NTD30N06T4G
NTD32N06-001	NTD32N06-1G	NTD32N06G	NTD32N06L	NTD32N06L-001
NTD32N06L-1G	NTD32N06LG	NTD32N06LT4G	NTD32N06T4G	NTD3808NT4G

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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